



BC846AW - BC848CW

NPN SURFACE MOUNT SMALL SIGNAL TRANSISTOR

Features

Ideally Suited for Automatic Insertion

Complementary PNP Types Available (BC856W-BC858W)

For Switching and AF Amplifier Applications

Lead Free/RoHS Compliant (Note 3)

"Green" Device (Note 4 and 5)

Mechanical Data

Case: SOT-323

Case Material: Molded Plastic, "Green" Molding

Compound, Note 5. UL Flammability

Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020C

Terminals: Solderable per MIL-STD-202, Method 208

Lead Free Plating (Matte Tin Finish annealed over

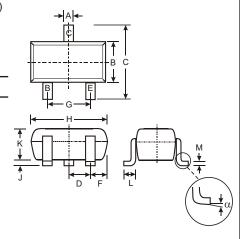
Alloy 42 leadframe).

Pin Connections: See Diagram

Marking Codes (See Table Below & Diagram on Page 2)

Ordering & Date Code Information: See Page 2

Weight: 0.006 grams (approximate)



SOT-323									
Dim	Min	Max							
Α	0.25	0.40							
В	1.15	1.35							
С	2.00	2.20							
D	0.65 Nominal								
E	0.30	0.40							
G	1.20	1.40							
Н	1.80	2.20							
J	0.0	0.10							
K	0.90	1.00							
L	0.25	0.40							
М	0.10	0.18							
	0	8							
All Dimensions in mm									

Marking Code (Note 2)										
Туре	Marking	Туре	Marking							
BC846AW	K1Q	BC847CW	K1M							
BC846BW	K1R	BC848AW	K1J, K1E, K1Q							
BC847AW	K1E, K1Q	BC848BW	K1K, K1F, K1R							
BC847BW	K1F, K1R	BC848CW	K1L, K1M							

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteris	tic	Symbol	Value	Unit		
Collector-Base Voltage	BC846 BC847 BC848	V_{CBO}	80 50 30	V		
Collector-Emitter Voltage	BC846 BC847 BC848	V _{CEO}	65 45 30	V		
Emitter-Base Voltage BC846, BC847 BC848		V _{EBO}	6.0 5.0	V		
Collector Current		Ic	100	mA		
Peak Collector Current		I _{CM}	200	mA		
Peak Emitter Current		I _{EM}	200	mA		
Power Dissipation (Note 1)		P _d	200	mW		
Thermal Resistance, Junction to A	Ambient (Note 1)	R _{JA}	625	°C/W		
Operating and Storage Temperatu	ure Range	T _j , T _{STG}	-65 to +150	°C		

- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. Current gain subgroup "C" is not available for BC846W.
- 3. No purposefully added lead.
- 4. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 5. Product manufactured with date code 0609 (week 9, 2006) and newer are built with Green Molding Compound. Product manufactured prior to date code 0609 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage (Note 6) BC846 BC847 BC848	V _{(BR)CBO}	80 50 30	_ _ _	_ _ _	V	I _C = 10 A, I _B = 0
Collector-Emitter Breakdown Voltage (Note 6) BC846 BC847 BC848	V _{(BR)CEO}	65 45 30	_ _ _	_ _ _	V	I _C = 10mA, I _B = 0
Emitter-Base Breakdown Voltage BC846, BC847 (Note 4) BC848	V _{(BR)EBO}	6 5	_		V	I _E = 1 A, I _C = 0
DC Current Gain Group A B (Note 6) C	h _{FE}	110 200 420	180 290 520	220 450 800	_	V _{CE} = 5.0V, I _C = 2.0mA
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(SAT)}	_	90 200	250 600	mV	I _C = 10mA, I _B = 0.5mA I _C = 100mA, I _B = 5.0mA
Base-Emitter Saturation Voltage (Note 6)	V _{BE(SAT)}	_	700 900	_	mV	I _C = 10mA, I _B = 0.5mA I _C = 100mA, I _B = 5.0mA
Base-Emitter Voltage (Note 6)	V _{BE(ON)}	580 —	660 —	700 770	mV	V _{CE} = 5.0V, I _C = 2.0mA V _{CE} = 5.0V, I _C = 10mA
Collector-Cutoff Current (Note 6)	I _{CBO}	_	_	15 5.0	nΑ μΑ	V _{CB} = 30V V _{CB} = 30V, T _A = 150°C
Gain Bandwidth Product	f⊤	100	300	_	MHz	V _{CE} = 5.0V, I _C = 10mA, f = 100MHz
Collector-Base Capacitance	C _{CBO}	_	3.0	4.5	pF	V _{CB} = 10V, f = 1.0MHz
Noise Figure	NF	_	_	10	dB	$V_{CE} = 5V, I_{C} = 200\mu A,$ $R_{S} = 2.0k$ f = 1.0kHz, f = 200Hz

Ordering Information (Note 5 & 7)

Device	Packaging	Shipping			
BC84xxW-7-F*	SOT-323	3000/Tape & Reel			

^{*}xx = device type, e.g. BC846AW-7.

Note:

- 5. Product manufactured with date code 0609 (week 9, 2006) and newer are built with Green Molding Compound. Product manufactured prior to date code 0609 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.
- 6. Short duration pulse test to minimize self-heating effect.
- 7. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

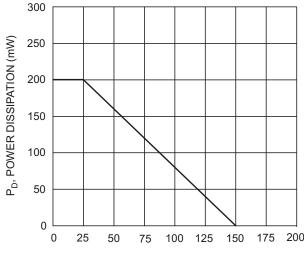
Marking Information



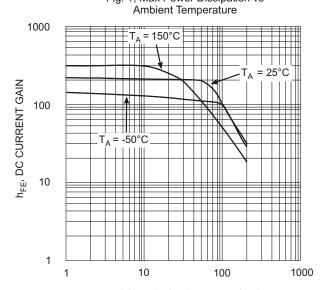
Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	М	N	Р	R	S	Т	U	V	W	Х	Y	Z
Month			Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	0	ct	Nov	Dec
	Code		1	2	3	4	5	6	7	8	9)	N	D





T_A, AMBIENT TEMPERATURE (°C) Fig. 1, Max Power Dissipation vs



I_C, COLLECTOR CURRENT (mA) Fig. 3, DC Current Gain vs. Collector Current

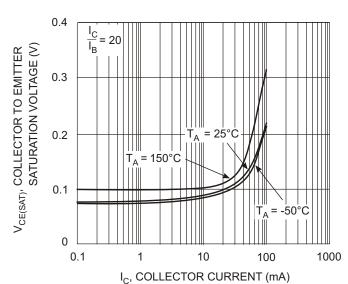
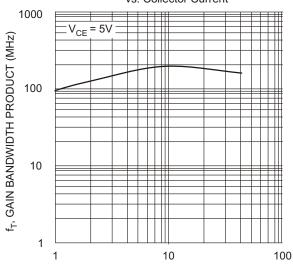


Fig. 2 Collector Emitter Saturation Voltage vs. Collector Current



I_C, COLLECTOR CURRENT (mA)
Fig. 4, Gain Bandwidth Product vs Collector Current

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